

Approval Sheet

(產品承認書)

產品名稱 (Product):

Bluetooth Low Energy Module

產品型號 (Model No.):

MDBT42TV Series (Chip Antenna)

MDBT42TV – P Series (PCB Antenna)

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1. Overall Introduction

Raytac's MDBT42TV & MDBT42TV-P is a BT 5.1 stack (Bluetooth low energy or BLE) module designed based on **Nordic nRF52805 SoC solution**, which incorporates: **GPIO**, **SPI**, **UART**, **I2C**, and **ADC** interfaces for connecting peripherals and sensors.

Features:

- 1. Dual Transmission mode of BLE & 2.4Ghz RF upon customer preference.
- 2. Compact size with (L) 8.3 x (W) 5.8 x (H) 1.3 mm.
- 3. Low power requirements, ultra-low peak, average and idle mode power consumption.
- 4. Be compatible with a large installed base of mobile phones, tablets and computers.
- 5. Fully coverage of BLE software stack.
- 6. BLE & RF transmission switching helps products fit all operation system and most hardware.

1.1. Application

- Data bridge
- Proprietary protocol devices
- Network processor
- Beacons
- Smart Home sensors
- Presenters/Stylus
- Health monitoring
- Drug delivery
- Asset tags
- Toys
- Retail tags and labels

1.2. Features

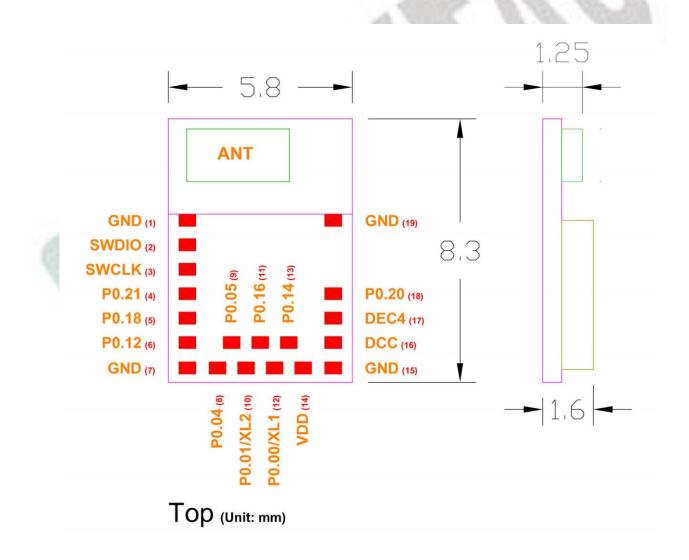
- Multi-protocol 2.4GHz radio
- 32-bit ARM Cortex M4 processor
- 192KB flash programmed memory and 24KB RAM
- · Software stacks available as downloads
- Application development independent from protocol stack
- On-air compatible with nRF51, nRF24AP and nRF24L series
- Programmable output power from +4dBm to -20dBm
- RSSI
- RAM mapped FIFOs using EasyDMA
- Flexible and configurable 10 pin GPIO
- Programmable peripheral interface PPI
- Full set of digital interface all with Easy DMA including:
 - 1 x Hardware SPI master ; 1 x Hardware SPI slave
 - 1 x two-wire master ; 1 x two-wire slave
 - 1 x UART (CTS / RTS)
- 2 channel 12-bit / 200KSPS ADC
- 128-bit AES ECB / CCM / AAR co-processor
- Low power 32MHz crystal and RC oscillators
- Wide supply voltage range 1.7V to 3.6V
- On-chip DC/DC buck converter
- Individual power management for all peripherals
- Timer counter
 - 3x 32-bit
 - 2 x 24-bit RTC

2. Product Dimension

2.1. PCB Dimensions & Pin Indication

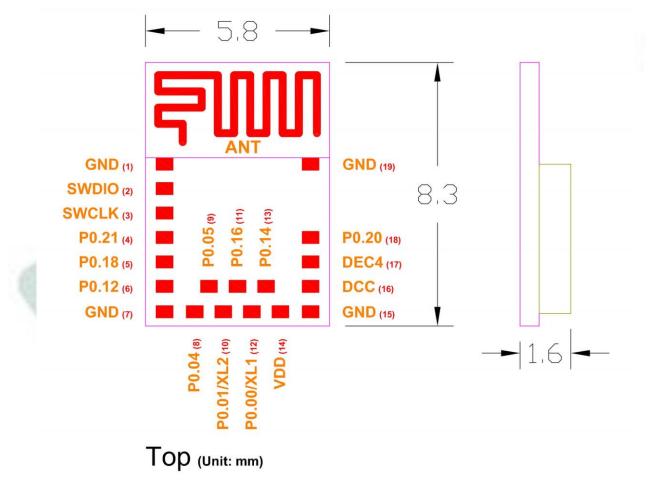
• MDBT42TV

<u>PCB Size (in mm)</u>					
	Min.	Norm	MAX.		
L		8.3			
w	- 0.15	5.8	+ 0.2		
н	-	1.3	. 8		



• <u>MDBT42TV-P</u>

PCB Size (in mm)					
	Min.	Norm	MAX.		
L		8.3			
w	- 0.15	5.8	+ 0.2		
н	_	1.3			

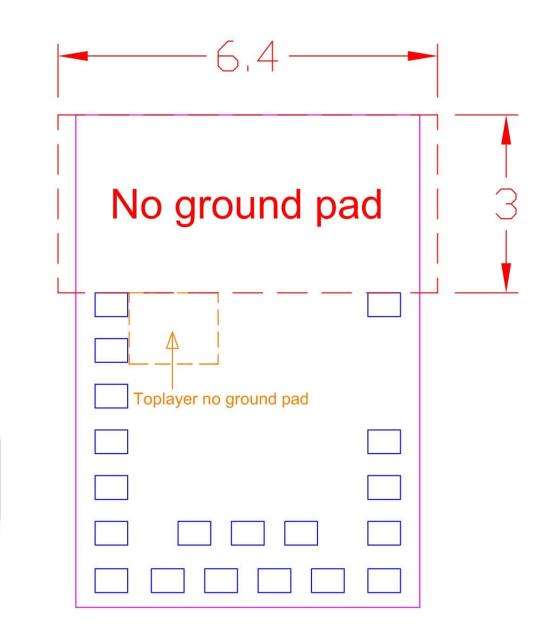


R.A.

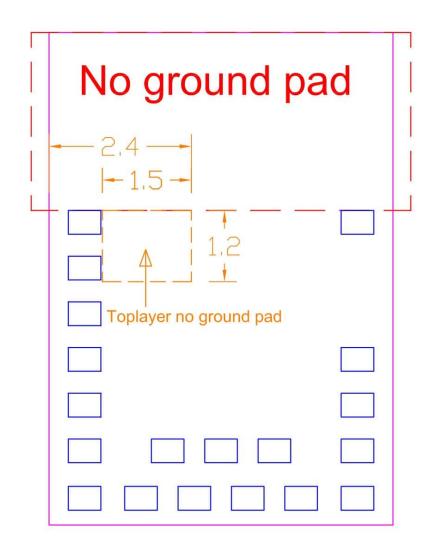
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2.2. Recommended Layout of Solder Pad

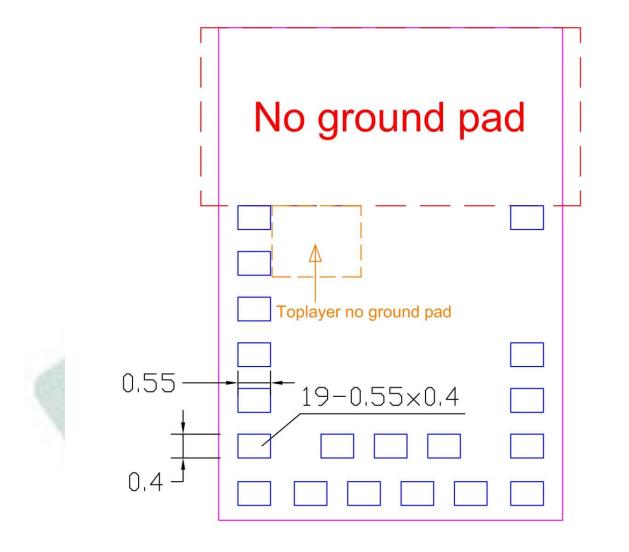
Graphs are all in Top View, Unit in mm.

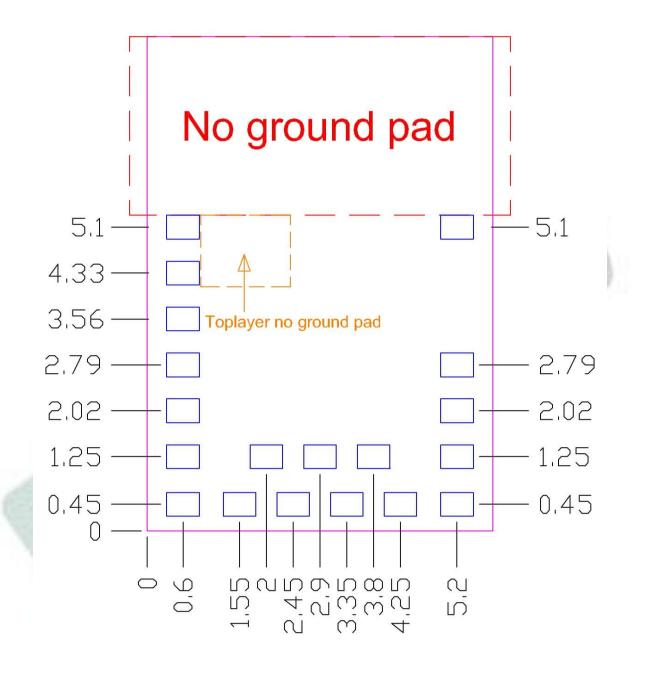


No ground pad



Toplayer no ground pad





Top View (Unit: mm) recommended solder pad layout

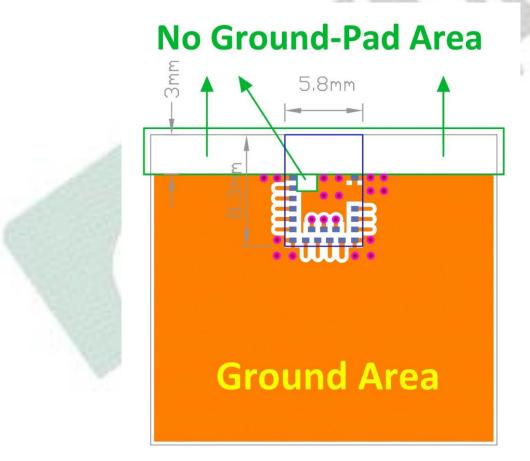
2.3. RF Layout Suggestion (aka Keep-Out Area)

Please follow below instruction to have better wireless performance. Make sure to keep the "No-Ground-Pad" as wider as possible when there is no enough space in your design.

No-Ground Pad should be included in the corresponding position of the antenna in **EACH LAYER**.

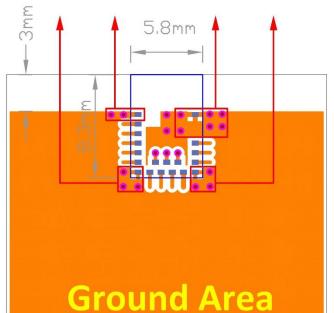
Place the module towards the edge of PCB to have better performance than placing it on the center.

Welcome to send us your layout in PDF for review at <u>service@raytac.com</u> or your contact at Raytac with title "<u>Layout reviewing –Raytac model no.–YOUR company's name</u>".



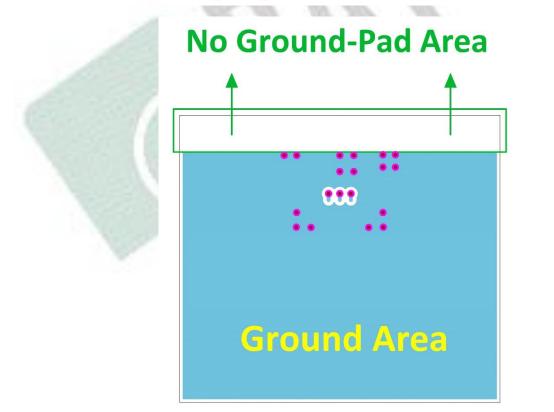
Top layer

Please add via holes in GROUND area as many as possible, especially around the four corners.





Top layer



Bottom layer

Examples of "NOT RECOMMENDED" layout



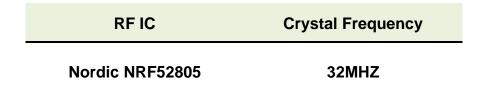
2.4. Footprint & Design Guide

Please visit "<u>Support</u>" page of our website to download. The package includes footprint, 2D/3D drawing, reflow graph and recommended spec for external 32.768khz.

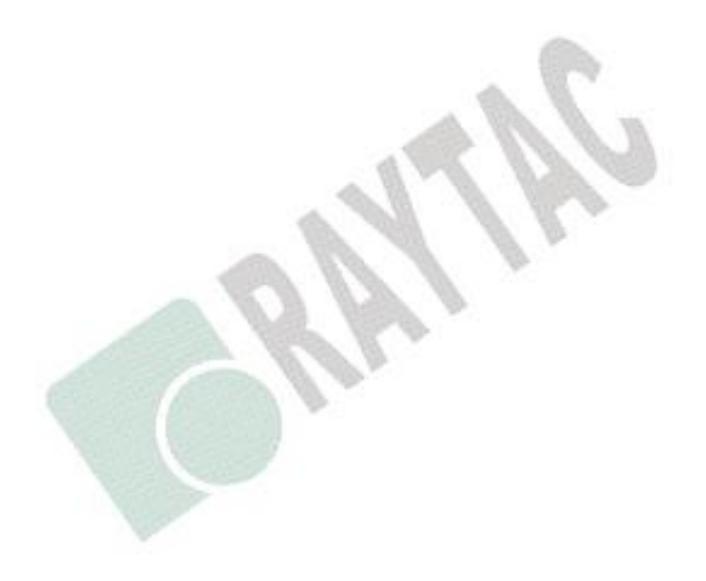
2.5. Pin Assignment

Pin No.	Name	Pin function	Description
(1)	GND	Ground	The pad must be connected to a solid ground plane
(2)	SWDIO	Digital I/O	Serial Wire debug I/O for debug and programming
(3)	SWDCLK	Digital input	Serial Wire debug clock input for debug and programming
	P0.21	Digital I/O	General-purpose digital I/O
(4)	RESET		Configurable as system RESET pin
(5)	P0.20	Digital I/O	General-purpose digital I/O
(6)	P0.14	Digital I/O	General-purpose digital I/O
(7)	P0.18	Digital I/O	General-purpose digital I/O
(8)	P0.16	Digital I/O	General-purpose digital I/O
(9)	P0.12	Digital I/O	General-purpose digital I/O
(10)	GND	Ground	The pad must be connected to a solid ground plane
(4.4)	P0.05	Digital I/O	General-purpose digital I/O
(11)	AIN3	Analog input	SAADC input
(4.2)	P0.04	Digital I/O	General-purpose digital I/O
(12)	AIN2	Analog input	SAADC input
(4.0)	P0.01	Digital I/O	General-purpose digital I/O
(13)	XL2	Analog input	Connection to 32.768khz crystal (LFXO)
(4.0)	P0.00	Digital I/O	General-purpose digital I/O
(14)	XL1	Analog input	Connection to 32.768khz crystal (LFXO)
(15)	VDD	Power	Power-supply pin
(16)	GND	Ground	The pad must be connected to a solid ground plane
(17)	DCC	Power	DC/DC converter output pin
(18)	DEC4	Power	1V3 regulator supply decoupling. Input from DC/DC converter. Output from 1V3 LDO
(19)	GND	Ground	The pad must be connected to a solid ground plane

3. Main Chip Solution



32MHz crystal is already inside the module.



4. Specification

Any technical spec shall refer to Nordic's official documents as final reference.

4.1. Absolute Maximum Ratings

	Note	Min.	Max.	Unit
Supply voltages				
VDD		-0.3	+3.9	V
VSS			0	V
I/O pin voltage				
V _{I/O} , VDD ≤3.6 V		-0.3	VDD + 0.3	V
V _{I/O} , VDD >3.6 V		-0.3	3.9	V
Environmental WLCSP package				
Storage temperature		-40	+125	°C
MSL	Moisture Sensitivity Level		1	
ESD HBM	Human Body Model		3	kV
ESD HBM Class	Human Body Model Class		2	
ESD CDM	Charged Device Model		1	kV
Flash memory				
Endurance		10 000		write/erase cycles
Retention at 85 °C		10		years

4.2. Operation Conditions

Symbol	Parameter	Min.	Nom.	Max.	Units
VDD	Supply voltage, independent of DCDC enable	1.7	3.0	3.6	V
t _{R_VDD}	Supply rise time (0 V to 1.7 V)			60	ms
ТА	Operating temperature	-40	25	85	°C

Important: The on-chip power-on reset circuitry may not function properly for rise times longer than the specified maximum.

4.3. Electrical Specifications

4.3.1. General Radio Characteristics

Symbol	Description	Min.	Тур.	Max.	Units
f _{OP}	Operating frequencies	2360		2500	MHz
f _{PLL,CH,SP}	PLL channel spacing		1		MHz
f _{delta,1m}	Frequency deviation @ 1 Mbps		±170		kHz
f _{delta,ble,1M}	Frequency deviation @ BLE 1 Mbps		±250		kHz
f _{delta,2m}	Frequency deviation @ 2 Mbps		±320		kHz
f _{delta,ble,2M}	Frequency deviation @ BLE 2 Mbps		±500		kHz
fsk _{BPS}	On-the-air data rate	1000		2000	kbps

4.3.2. Radio Current Consumption (Transmitter)

Symbol	Description	Min.	Тур.	Max.	Units
ITX,PLUS4dBM,DCDC	TX only run current (DCDC, 3V) P _{RF} =+4 dBm		7.0		mA
I _{TX,PLUS4dBM}	TX only run current P _{RF} = +4 dBm		15.4		mA
I _{TX,0dBM,DCDC}	TX only run current (DCDC, 3V)P _{RF} = 0dBm		4.6		mA
I _{TX,0dBM}	TX only run current P _{RF} = 0dBm		10.1		mA
I _{TX,MINUS4dBM,DCDC}	TX only run current DCDC, 3V P_{RF} = -4dBm		3.6		mA
I _{TX,MINUS4dBM}	TX only run current P _{RF} = -4 dBm		7.8		mA
ITX,MINUS8dBM,DCDC	TX only run current DCDC, 3V P_{RF} = -8 dBm		3.2		mA
I _{TX,MINUS8dBM}	TX only run current P _{RF} = -8 dBm		6.8		mA
ITX,MINUS12dBM,DCDC	TX only run current DCDC, 3V P_{RF} = -12 dBm		2.9		mA
I _{TX,MINUS12dBM}	TX only run current P _{RF} = -12 dBm		6.2		mA
ITX,MINUS16dBM,DCDC	TX only run current DCDC, 3V $\mathrm{P_{RF}}$ = -16 dBm		2.7		mA
I _{TX,MINUS16dBM}	TX only run current P _{RF} = -16 dBm		5.7		mA
ITX,MINUS20dBM,DCDC	TX only run current DCDC, 3V P_{RF} = -20 dBm		2.5		mA
I _{TX,MINUS20dBM}	TX only run current P _{RF} = -20 dBm		5.4		mA
ITX,MINUS40dBM,DCDC	TX only run current DCDC, 3V P_{RF} = -40 dBm		2.1		mA
I _{TX,MINUS40dBM}	TX only run current P _{RF} = -40 dBm		4.3		mA
I _{START,TX,DCDC}	TX start-up current DC/DC, 3 V, P _{RF} = 4 dBm				mA
I _{START,TX}	TX start-up current, P _{RF} = 4 dBm				mA

4.3.3. Radio Current Consumption (Receiver)

Symbol	Description	Min.	Тур.	Max.	Units
I _{RX,1M,DCDC}	RX only run current (DC/DC, 3 V) 1 Mbps/1 Mbps BLE		4.6		mA
I _{RX,1M}	RX only run current (LDO, 3 V) 1 Mbps/1 Mbps BLE		10.0		mA
I _{RX,2M,DCDC}	RX only run current (DC/DC, 3 V) 2 Mbps/2 Mbps BLE		5.2		mA
I _{RX,2M}	RX only run current (LDO, 3 V) 2 Mbps/2 Mbps BLE		11.2		mA
ISTART,RX,1M,DCDC	RX start-up current (DC/DC, 3 V) 1 Mbps/1 Mbps BLE		3.5		mA
I _{START,RX,1M}	RX start-up current 1 Mbps/1 Mbps BLE		6.7		mA

4.3.4. Transmitter Specification

Symbol	Description	Min.	Тур.	Max.	Units
P _{RF}	Maximum output power		4		dBm
P _{RFC}	RF power control range		24		dB
P _{RFCR}	RF power accuracy			±4	dB
P _{RF1,1}	1st Adjacent Channel Transmit Power 1 MHz (1 Mbps)		-25		dBc
P _{RF2,1}	2nd Adjacent Channel Transmit Power 2 MHz (1 Mbps)		-50		dBc
P _{RF1,2}	1st Adjacent Channel Transmit Power 2 MHz (2 Mbps)		-25		dBc
P _{RF2,2}	2nd Adjacent Channel Transmit Power 4 MHz (2 Mbps)		-50		dBc

4.3.5. Receiver Operation

Symbol	Description	Min.	Тур.	Max.	Units
P _{RX,MAX}	Maximum received signal strength at < 0.1% PER		0		dBm
P _{SENS,IT,1M}	Sensitivity, 1 Mbps nRF mode ideal transmitter 1		-94		dBm
P _{SENS,IT,2M}	Sensitivity, 2 Mbps nRF mode ideal transmitter ¹		-91		dBm
P _{SENS,IT,SP,1M,BLE}	Sensitivity, 1 Mbps BLE ideal transmitter, packet length \leq 37 bytes BER=1E-3 ²		-97		dBm
P _{SENS} ,IT,LP,1M,BLE	Sensitivity, 1 Mbps BLE ideal transmitter, packet length \ge 128 bytes BER=1E-4 ³		-96		dBm
P _{SENS,IT,SP,2M,BLE}	Sensitivity, 2 Mbps BLE ideal transmitter, packet length \leq 37		-94		dBm
	bytes				

1. Typical sensitivity applies when ADDRO is used for receiver address correlation. When ADDR [1...7] are used for receiver address correlation, the typical sensitivity for this mode is degraded by 3dB.

2. As defined in the Bluetooth Core Specification v4.0 Volume 6: Core System Package (Low Energy Controller Volume).

3. Equivalent BER limit < 10E-04.

4.3.6. RX Selectivity

Symbol	Description	Min.	Тур.	Max.	Units
C/I _{1M,co-channel}	1Mbps mode, co-channel interference		9		dB
C/I _{1M,-1MHz}	1 Mbps mode, Adjacent (-1 MHz) interference		-2		dB
C/I _{1M,+1MHz}	1 Mbps mode, Adjacent (+1 MHz) interference		-10		dB
C/I _{1M,-2MHz}	1 Mbps mode, Adjacent (-2 MHz) interference		-19		dB
C/I _{1M,+2MHz}	1 Mbps mode, Adjacent (+2 MHz) interference		-42		dB
C/I _{1M,-3MHz}	1 Mbps mode, Adjacent (-3 MHz) interference		-38		dB
C/I _{1M,+3MHz}	1 Mbps mode, Adjacent (+3 MHz) interference		-48		dB
C/I _{1M,±6MHz}	1 Mbps mode, Adjacent (≥6 MHz) interference		-50		dB
C/I _{1MBLE,co-channel}	1 Mbps BLE mode, co-channel interference		6		dB
C/I _{1MBLE,-1MHz}	1 Mbps BLE mode, Adjacent (-1 MHz) interference		-2		dB
C/I _{1MBLE,+1MHz}	1 Mbps BLE mode, Adjacent (+1 MHz) interference		-9		dB
C/I _{1MBLE,-2MHz}	1 Mbps BLE mode, Adjacent (-2 MHz) interference		-22		dB
C/I _{1MBLE,+2MHz}	1 Mbps BLE mode, Adjacent (+2 MHz) interference		-46		dB
C/I _{1MBLE,>3MHz}	1 Mbps BLE mode, Adjacent (≥3 MHz) interference		-50		dB
C/I _{1MBLE,image}	Image frequency interference		-22		dB
C/I _{1MBLE,image,1MHz}	Adjacent (1 MHz) interference to in-band image frequ	iency	-35		dB
C/I _{2M,co-channel}	2 Mbps mode, co-channel interference		10		dB
C/I _{2M,-2MHz}	2 Mbps mode, Adjacent (-2 MHz) interference		6		dB
C/I _{2M,+2MHz}	2 Mbps mode, Adjacent (+2 MHz) interference		-14		dB
C/I _{2M,-4MHz}	2 Mbps mode, Adjacent (-4 MHz) interference		-20		dB
C/I _{2M,+4MHz}	2 Mbps mode, Adjacent (+4 MHz) interference		-44		dB
C/I _{2M,-6MHz}	2 Mbps mode, Adjacent (-6 MHz) interference		-42		dB
C/I _{2M,+6MHz}	2 Mbps mode, Adjacent (+6 MHz) interference		-47		dB
C/I _{2M,≥12MHz}	2 Mbps mode, Adjacent (≥12 MHz) interference		-52		dB
C/I _{2MBLE,co-channel}	2 Mbps BLE mode, co-channel interference		6		dB
C/I _{2MBLE} ,-2MHz	2 Mbps BLE mode, Adjacent (-2 MHz) interference		-2		dB
C/I _{2MBLE,+2MHz}	2 Mbps BLE mode, Adjacent (+2 MHz) interference		-12		dB
C/I _{2MBLE} ,-4MHz	2 Mbps BLE mode, Adjacent (-4 MHz) interference		-22		dB
C/I _{2MBLE,+4MHz}	2 Mbps BLE mode, Adjacent (+4 MHz) interference		-46		dB
C/I _{2MBLE,≥6MHz}	2 Mbps BLE mode, Adjacent (≥6 MHz) interference		-50		dB
C/I _{2MBLE,image}	Image frequency interference		- 2 9		dB
C/I _{2MBLE,image} , 2MHz	Adjacent (2 MHz) interference to in-band image frequ	iency	-44		dB

Remark: Wanted signal level at PIN = -67 dBm. One interferer is used, having equal modulation as the wanted signal. The input power of the interferer where the sensitivity equals BER = 0.1% is presented.

4.3.7. RX Intermodulation

Symbol	Description	Min.	Тур.	Max.	Units
PIMD,5TH,1M	IMD performance, 1 Msps, 5th offset channel, Packet length		-33		dBm
	<= 37 bytes				
PIMD,5TH,1M,BLE	IMD performance, BLE 1 Msps, 5th offset channel, Packet		-30		dBm
	length <= 37 bytes				
PIMD,5TH,2M	IMD performance, 2 Msps, 5th offset channel, Packet length		-33		dBm
	<= 37 bytes				
P _{IMD,5TH,2M,BLE}	IMD performance, BLE 2 Msps, 5th offset channel, Packet		-31		dBm
	length <= 37 bytes				

Remark: Wanted signal level at PIN = -64dBm. Two interferers with equal input power are used. The interferer closest in frequency is not modulated, the other interferer is modulated equal with the wanted signal. The input power of the interferers where the sensitivity equals BER = 0.1% is presented.

4.3.8. Radio Timing Parameters

Symbol	Description	Min.	Тур.	Max.	Units
t _{TXEN,BLE,1M}	Time between TXEN task and READY event after channel		140		μs
	FREQUENCY configured (1 Mbps BLE and 150 µs TIFS)				
t _{TXEN,FAST,BLE,1M}	Time between TXEN task and READY event after channel		40		μs
	FREQUENCY configured (1 Mbps BLE with fast ramp-up and				
	150 μs TIFS)				
t _{TXDIS,BLE,1M}	When in TX, delay between DISABLE task and DISABLED		6		μs
	event for MODE = Nrf_1Mbit and MODE = Ble_1Mbit				
t _{RXEN,BLE,1M}	Time between the RXEN task and READY event after channel		140		μs
	FREQUENCY configured (1 Mbps BLE)				
t _{RXEN} ,FAST,BLE,1M	Time between the RXEN task and READY event after channel		40		μs
	FREQUENCY configured (1 Mbps BLE with fast ramp-up)				
t _{RXDIS,BLE,1M}	When in RX, delay between DISABLE task and DISABLED		0		μs
	event for MODE = Nrf_1Mbit and MODE = Ble_1Mbit				
t _{txdis,ble,2M}	When in TX, delay between DISABLE task and DISABLED		4		μs
	event for MODE = Nrf_2Mbit and MODE = Ble_2Mbit				
t _{RXDIS,BLE,2M}	When in RX, delay between DISABLE task and DISABLED		0		μs
	event for MODE = Nrf_2Mbit and MODE = Ble_2Mbit				

4.3.9. RSSI Specifications

Symbol	Description	Min.	Тур.	Max.	Units
RSSI _{ACC}	RSSI accuracy 18		±2		dB
RSSIRESOLUTION	RSSI resolution		1		dB
RSSIPERIOD	RSSI sampling time from RSSI_START task		0.25		μs
RSSI _{SETTLE}	RSSI settling time after signal level change		15		μs

4.3.10. CPU

Symbol	Description	Min.	Тур.	Max.	Units
W _{FLASH}	CPU wait states, running from flash	0		2	
WRAM	CPU wait states, running from RAM			0	
CM _{FLASH}	CoreMark ¹ , running from flash		144		CoreMark
CM _{FLASH} /MHz	CoreMark per MHz, running from flash		2.25		Corel
					MHz
CM _{FLASH} /mA	CoreMark per mA, running from flash, DCDC 3V		65		CoreMark/mA
	the second se		100 million		

4.3.11. Power Management

Symbol	Description	Min.	Тур.	Max.	Units
ION_RAMOFF_EVENT	System ON, no RAM retention, wake on any event		0.6		μA
ION_RAMON_EVENT	System ON, full 24 kB RAM retention, wake on any event		0.8		μΑ
ION_RAMON_POF	System ON, full 24 kB RAM retention, wake on any event,		0.8		μΑ
	power-fail comparator enabled				
ION_RAMON_GPIOTE	System ON, full 24 kB RAM retention, wake on GPIOTE input (event mode)		3.3		μΑ
ION_RAMON_GPIOTEPOR	RTSystem ON, full 24 kB RAM retention, wake on GPIOTE PORT event		0.8		μΑ
ION_RAMOFF_RTC	System ON, no RAM retention, wake on RTC (running from LFRC clock)		1.4		μΑ
ION_RAMON_RTC	System ON, full 24 kB RAM retention, wake on RTC (running from LFRC clock)		1.5		μΑ
IOFF_RAMOFF_RESET	System OFF, no RAM retention, wake on reset		0.3		μΑ
IOFF_RAMON_RESET	System OFF, full 24 kB RAM retention, wake on reset		0.5		μΑ
ION_RAMON_RTC_LEXO	System ON, full 24 kB RAM retention, wake on RTC (running from LFXO clock)		1.1		μΑ
ION_RAMOFF_RTC_LEXO	System ON, no RAM retention, wake on RTC (running from LFXO clock)		1.0		μΑ

5. FCC Compliance

This equipment has been tested and found to comply with the limits for a Class digital device, pursuant to Part 15 of the FCC rules. These limits are designed to provide reasonable protection against harmful interference in a residential installation. This equipment generates uses and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to the radio communications. However, there are no guarantees that interference will not occur in a particular installation.

Troubleshooting

If this equipment does cause harmful interference to radio reception, which can be determined by turning the equipment off and on, the user is encouraged to correct the interference by one or more of the following instructions.

- · Reorient or relocate the receiving antenna.
- · Increase the separation between the equipment and receiver.
- · Consult dealer or an experienced radio technician.

Conditions

Operation is subject to the following conditions

· This device may not cause harmful interference.

 \cdot This device must accept any interference received, including interference that may cause undesired operation.

FCC Caution

This device complies with Part 15 of the FCC rules. Operation is subject to the following two conditions: (1) this device may not cause harmful interference, and (2) this device must accept any interference received, including interference that may cause undesired operation.

Any changes or modifications not expressly approved by the party responsible for compliance could void the authority to operate equipment.

RF Exposure

FCC RF Radiation Exposure Statement:

- 1. This Transmitter must not be co-located or operating in conjunction with any other antenna or transmitter.
- For body worn operation, this device has been tested and meets FCC RF exposure guidelines. When used with an accessory that contains metal may not ensure compliance with FCC RF exposure guidelines.

This device complies with Part 15 of the FCC Rules. Operation is subject to the following two conditions:

- 1) this device may not cause harmful interference and
- 2) this device must accept any interference received, including interference that may cause undesired operation.

Required End Product Labeling

Any device incorporating this module must include an external, visible, permanent marking or label which states: "Contains FCC ID: SH6MDBT42TV"

Applicable FCC Rules

This module has been tested and found to comply with the following requirements for Modular Approval.

 Part 15.247 - Operation within the bands 902-928 MHz, 2400-2483.5 MHz, and 5725-5850 MHz.

Additional testing, Part 15 Subpart B disclaimer

The modular transmitter is only FCC authorized for the specific rule parts (i.e., FCC transmitter rules) listed on the grant, and that the host product manufacturer is responsible for compliance to any other FCC rules that apply to the host not covered by the modular transmitter grant of certification.

The final host product still requires Part 15 Subpart B compliance testing with the modular transmitter installed.

Test Modes

This device uses various test mode programs for test set up which operate separate from production firmware. Host integrators should contact the grantee for assistance with test modes needed for module/host compliance test requirements.

Antennas

The following external antenna type have been approved for use with this module.

Radio	Model	Antenna Type	Freq. (MHz)	Max. Peak Antenna Gain (dBi)
BLE	MDBT42TV	Chip	2402-2480	-5.81
BLE	MDBT42TV-P	PCB	2402-2480	-6.50

In the end product, the antenna(s) used with this transmitter must be installed and must not be co-located or operation in conjunction with any other antenna or transmitter except in

accordance with FCC multi-transmitter product procedures.

End Product Labeling

This transmitter module is authorized only for use in device where the antenna may be installed such that 5mm may be maintained between the antenna and users. The final end product must be labeled in a visible area with the following:

Contains FCC ID: SH6MDBT42TV

Manual Information to the End User

The OEM integrator has to be aware not to provide information to the end user regarding how to install or remove this RF module in the user's manual of the end product which integrates this module. The end user manual shall include all required regulatory information/warming as shown in this manual.

6. IC Caution

This device contains licence-exempt transmitter(s)/receiver(s) that comply with Innovation, Science and Economic Development Canada's licence-exempt RSS(s). Operation is subject to the following two conditions:

- 1. This device may not cause interference.
- 2. This device must accept any interference, including interference that may cause undesired operation of the device.

Avis Canadien

L'émetteur/récepteur exempt de licence contenu dans le présent appareil est conforme aux CNR d'Innovation, Sciences et Développement économique Canada applicables aux appareils radio exempts de licence. L'exploitation est autorisée aux deux conditions suivantes :

- 1. L'appareil ne doit pas produire de brouillage;
- 2. L'appareil doit accepter tout brouillage radioélectrique subi, même si le brouillage est susceptible d'en compromettre le fonctionnement.

RF Radiation Exposure Statement:

- 1. To comply with the Canadian RF exposure compliance requirements, this device and its antenna must not be co-located or operating in conjunction with any other antenna or transmitter.
- 2. For body worn operation, this phone has been tested and meets RF exposure guidelines when used with an accessory that contains no metal. Use of other accessories may not ensure compliance with RF exposure guidelines.

Déclaration de l'exposition aux radiations RF:

- 1. Pour se conformer aux exigences de conformité RF canadienne l'exposition, cet appareil et son antenne ne doivent pas être co-localisés ou fonctionnant en conjonction avec une autre antenne ou transmetteur.
- Pour le fonctionnement du corps, ce téléphone a été testé et répond aux directives d'exposition RF lorsqu'il est utilisé avec un accessoire qui ne contient pas de métal. Utilisation d'autres accessoires peut ne pas assurer le respect des directives d'exposition RF.

Required End Product Labeling

Any device incorporating this module must include an external, visible, permanent marking or label which states: "Contains IC : 8017A-MDBT42TV"

Obligation d'étiquetage du produit final:

Tout dispositif intégrant ce module doit comporter un externe, visible, marquage permanent ou une étiquette qui dit: "Contient IC : 8017A-MDBT42TV"

Antennas

This radio transmitter has been approved by Industry Canada to operate with the antenna types listed below with the maximum permissible gain indicated. Antenna types not included in this list, having a gain greater than the maximum gain indicated for that type, are strictly prohibited for use with this device.

Antennes

Cet émetteur radio a été approuvé par Industrie Canada pour fonctionner avec les types d'antenne énumérés ci-dessous avec le gain maximal admissible indiqué . types d'antennes non inclus dans cette liste , ayant un gain supérieur au gain maximum indiqué pour ce type , sont strictement interdits pour une utilisation avec cet appareil.

Radio	ISED HVIN	Antenna Type	Freq. (MHz)	Max. Peak Antenna Gain (dBi)
BLE	MDBT42TV	Chip	2402-2480	-5.81
BLE	MDBT42TV-P	PCB	2402-2480	-6.50



7.NCC 警語

根據 NCC 低功率電波輻射性電機管理辨法規定

LP0002低功率射頻器材技術規範_章節 3.8.2

取得審驗證明之低功率射頻器材,非經核准,公司、商號或使用者均不得擅自變更頻率、加大 功率或變更原設計之特性及功能。

低功率射頻器材之使用不得影響飛航安全及干擾合法通信;經發現有干擾現象時,應立即停用, 並改善至無干擾時方得繼續使用。

前述合法通信,指依電信管理法規定作業之無線電通信。

低功率射頻器材須忍受合法通信或工業、科學及醫療用電波輻射性電機設備之干擾。

此模組於取得認證後將依規定於模組本體標示審驗合格標籤,並要求平台廠商於平台上標示。 「本產品內含射頻模組:ID 編號 XXXXX」字樣